

## Audio Amplification Transistor

### Features and Benefits

- LAPT (High frequency multi emitter transistor)
- Small package (TO-3P)
- High power handling capacity, 160 W
- Improved sound output by reduced on-chip impedance
- Complementary to 2SC6145A

### Package: 3-Lead TO-3P



*Not to scale*

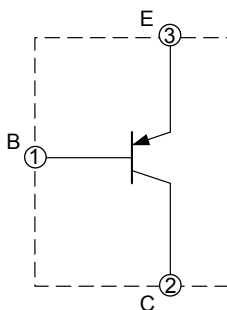
### Description

Sanken LAPT transistors have an innovative design, produced by adapting advancements in the unique Sanken thin-wafer production technology. These PNP power transistors achieve faster power-up by decreasing thermal resistance, and provide a higher avalanche breakdown voltage rating. The high power-handling capacity of the TO-3P package allows a smaller footprint on the circuit board layout. This series of transistors is very well suited not only for multichannel applications for AV (audio-visual) amplifiers and receivers, but also for parallel connection applications for PA (professional audio system) amplifiers.

Applications include the following:

- Single transistors for audio amplifiers
- Home audio amplifiers
- Professional audio amplifiers
- Automobile audio amplifiers
- Audio market
- Single transistors for general purpose

### Equivalent Circuit



## Selection Guide

| Part Number | Type | $h_{FE}$ Rating    | Packing            |
|-------------|------|--------------------|--------------------|
| 2SA2223A*   | PNP  | Range R: 40 to 80  | 30 pieces per tube |
|             |      | Range O: 50 to 100 |                    |
|             |      | Range Y: 70 to 140 |                    |

\*Specify  $h_{FE}$  range when ordering.

## Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

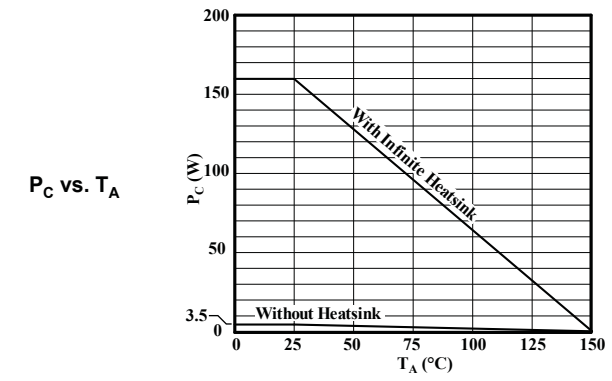
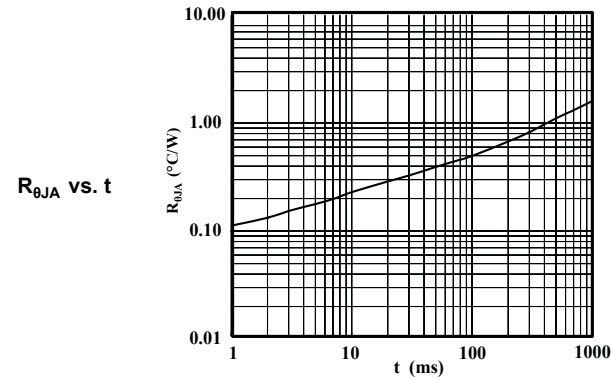
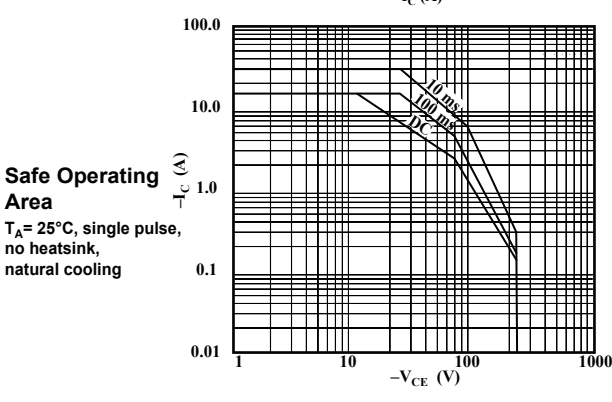
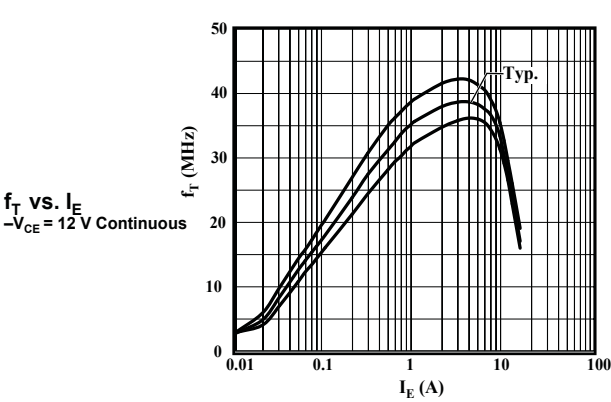
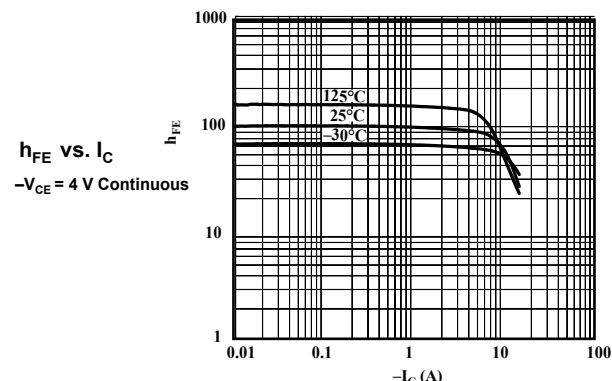
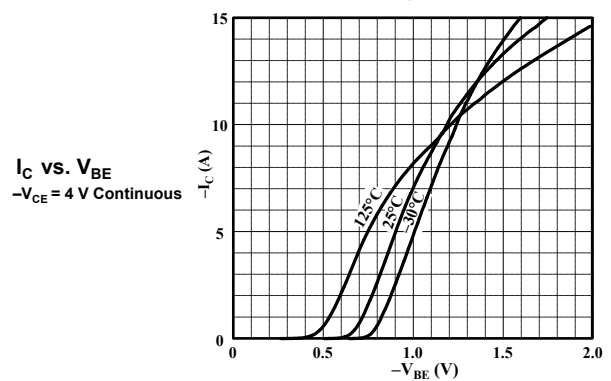
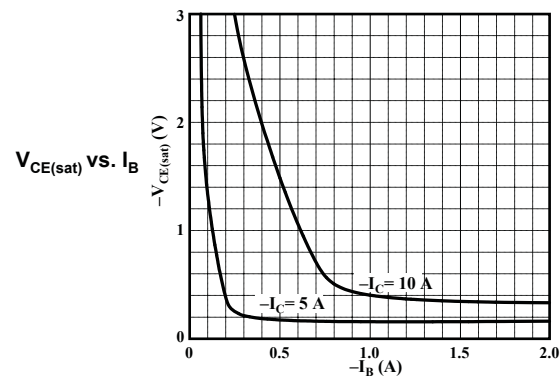
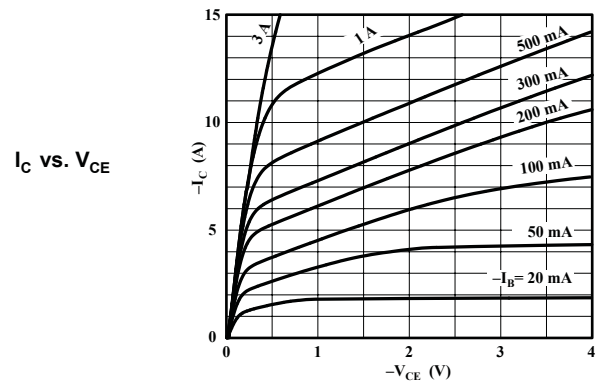
| Characteristic              | Symbol    | Remarks                       | Rating     | Unit             |
|-----------------------------|-----------|-------------------------------|------------|------------------|
| Collector-Base Voltage      | $V_{CBO}$ |                               | -260       | V                |
| Collector-Emitter Voltage   | $V_{CEO}$ |                               | -260       | V                |
| Emitter-Base Voltage        | $V_{EBO}$ |                               | -5         | V                |
| Collector Current           | $I_C$     |                               | -15        | A                |
| Base Current                | $I_B$     |                               | -4         | A                |
| Collector Power Dissipation | $P_C$     | $T_{CASE} = 25^\circ\text{C}$ | 160        | W                |
| Junction Temperature        | $T_J$     |                               | 150        | $^\circ\text{C}$ |
| Storage Temperature         | $T_{stg}$ |                               | -55 to 150 | $^\circ\text{C}$ |

## ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

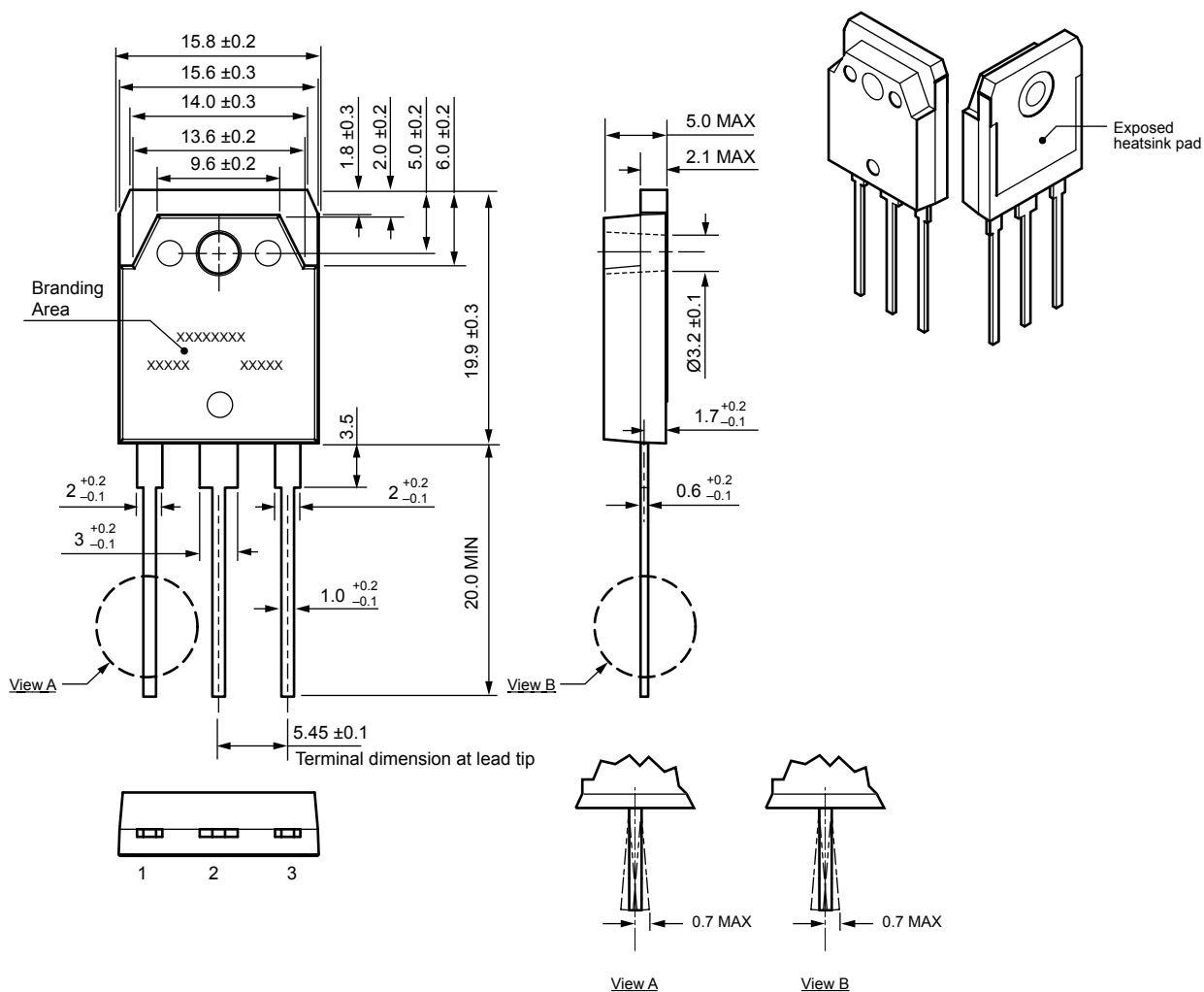
| Characteristic                       | Symbol        | Test Conditions                                             | Min. | Typ. | Max. | Unit          |
|--------------------------------------|---------------|-------------------------------------------------------------|------|------|------|---------------|
| Collector-Cutoff Current             | $I_{CBO}$     | $V_{CB} = -260\text{ V}$                                    | —    | —    | -10  | $\mu\text{A}$ |
| Emitter Cutoff Current               | $I_{EBO}$     | $V_{EB} = -5\text{ V}$                                      | —    | —    | -10  | $\mu\text{A}$ |
| Collector-Emitter Voltage            | $V_{(BR)CEO}$ | $I_C = -25\text{ mA}$                                       | -260 | —    | —    | V             |
| DC Current Transfer Ratio*           | $h_{FE}$      | $V_{CE} = -4\text{ V}, I_C = -5\text{ A}$                   | 40   | —    | 140  | —             |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C = -5\text{ A}, I_B = -0.5\text{ A}$                    | —    | —    | -0.5 | V             |
| Cutoff Frequency                     | $f_T$         | $V_{CE} = -12\text{ V}, I_E = 2\text{ A}$                   | —    | 35   | —    | MHz           |
| Output Capacitance                   | $C_{OB}$      | $V_{CB} = -10\text{ V}, I_E = 0\text{ A}, f = 1\text{ MHz}$ | —    | 500  | —    | pF            |

\* $h_{FE}$  rating: 40 to 80 (R brand on package), 50 to 100 (O), 70 to 140 (Y).

Performance Characteristics



## Package Outline Drawing, TO-3P



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side  
 Terminal core material: Cu  
 Terminal treatment: Ni plating and Pb-free solder dip  
 Leadform: 100  
 Package: TO-3P (M100)  
 Approximate weight: 6 g

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):  
 1st line, type: A2223A  
 2nd line left, lot: YM  
 Where: Y is the last digit of the year of manufacture  
 M is the month (1 to 9, O, N, D)  
 2nd line right, subtype: H  
 Where: H is the  $h_{FE}$  rating (O, R, or Y; for values see footnote, Electrical Characteristics table)



Leadframe plating Pb-free. Device composition includes high-temperature solder (Pb >85%), which is exempted from the RoHS directive.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

#### Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

#### Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

#### Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

| Type   | Suppliers                            |
|--------|--------------------------------------|
| G746   | Shin-Etsu Chemical Co., Ltd.         |
| YG6260 | Momentive Performance Materials Inc. |
| SC102  | Dow Corning Toray Co., Ltd.          |

#### Cautions for Mounting to a Heatsink

- When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05 mm or less.
- Please select suitable screws for the product shape. Do not

use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.

- Recommended screw torque: 0.686 to 0.882 N•m (7 to 9 kgf•cm).
  - Diameter of Heatsink Hole: < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.
  - For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.
- When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

#### Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:  
260±5°C 10±1 s (Flow, 2 times)  
350±5°C 3±0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 1.5 mm from the body of the products.

#### Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

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In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

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